

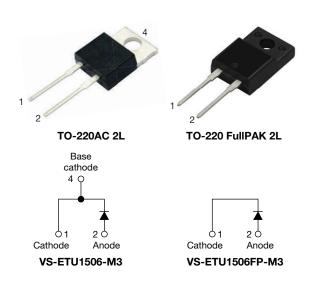
Vishay Semiconductors

RoHS COMPLIANT

HALOGEN

FREE

Ultra Fast Rectifier, 15 A FRED Pt®



PRIMARY CHARACTERISTICS				
Package	TO-220AC 2L, TO-220FullPAK 2L			
I _{F(AV)}	15 A			
V _R	600 V			
V _F at I _F	1.1 V			
t _{rr} (typ.)	24 ns			
T _J max.	175 °C			
Circuit configuration	Single			

FEATURES

- Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>



State of the art, ultralow V_F , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
A construction of factorized converting DC	I _{F(AV)}	T _C = 151 °C	15	А		
Average rectified forward current in DC FullPAK		T _C = 103 °C	13			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	160			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-		
Forward voltage	V _F	I _F = 15 A	-	1.35	1.9	V	
		I _F = 15 A, T _J = 150 °C	-	1.1	1.3		
Devenue le alcono everent	-	$V_R = V_R$ rated	-	0.01	15		
Reverse leakage current I _R		T _J = 150 °C, V _R = V _R rated	-	20	200	μA	
Junction capacitance	C _T	V _R = 600 V	-	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	



VS-ETU1506-M3,VS-ETU1506FP-M3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 100$	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		24	28	
Deverage receivers time		$I_F = 15 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	36	47	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	ns
		T _J = 125 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 200 \text{ A/µs}$ $V_R = 390 \text{ V}$	-	87	-	
Dools week your accument		T _J = 25 °C		-	5	-	А
Peak recovery current	I _{RRM}	T _J = 125 °C		-	9	-	
Deverse receives above	0	T _J = 25 °C		-	107	-	200
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	430	-	nC
Reverse recovery time	t _{rr}	T _J = 125 °C	$I_F = 15 \text{ A}$ $dI_F/dt = 800 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	53	-	ns
Peak recovery current	I _{RRM}			-	25	-	Α
Reverse recovery charge	Q _{rr}			-	730	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance,	D		ı	1.2	1.4	
junction to case FULL-PAK	R_{thJC}		-	3.7	4.3	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
\\/-:- -t			-	2	-	g
Weight			_	0.07	-	OZ.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking daying		Case style TO-220AC 2L	ETU1506			
Marking device		Case style TO-220 FullPAK 2L		ETU1	506FP	



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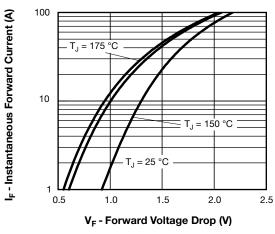


Fig. 1 - Typical Forward Voltage Drop Characteristics

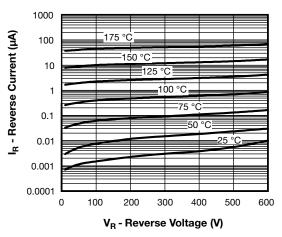


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

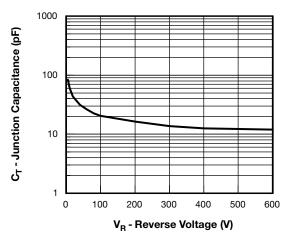


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

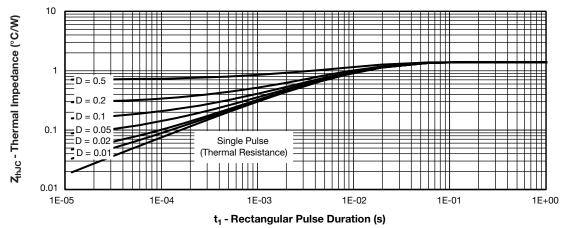


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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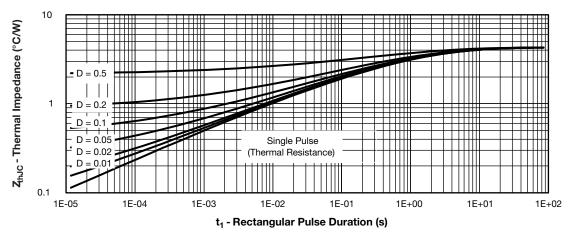


Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FullPAK)



Fig. 6 - Maximum Allowable Case Temperature vs.
Average Forward Current

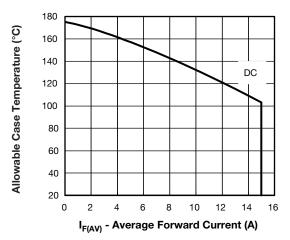


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FullPAK)

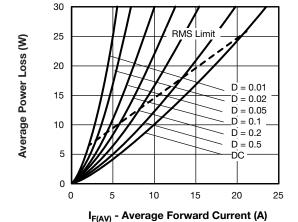


Fig. 8 - Forward Power Loss Characteristics



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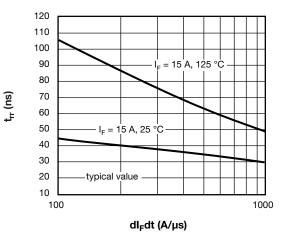


Fig. 9 - Typical Reverse Recovery vs. dl_F/dt

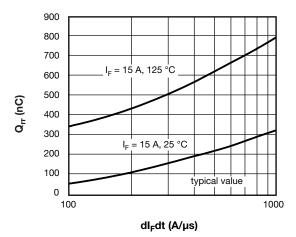
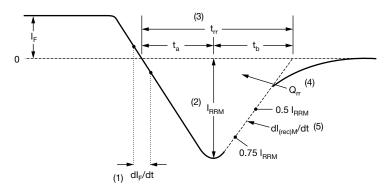


Fig. 10 - Typical Stored Charge vs. dl_F/dt



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

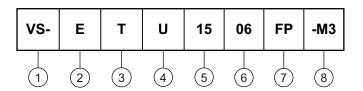
(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 11 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode

3 - T = TO-220

U = hyperfast recovery time

5 - Current code: 15 = 15 A

6 - Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-ETU1506-M3	50	1000	Antistatic plastic tube		
VS-ETU1506FP-M3	50	1000	Antistatic plastic tube		

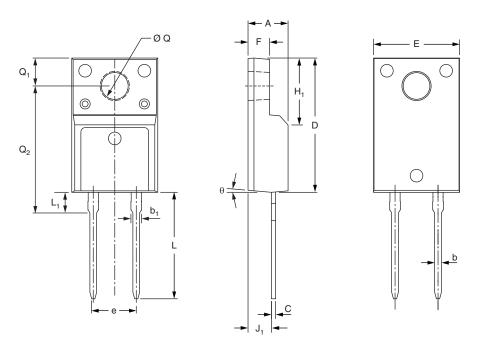
LINKS TO RELATED DOCUMENTS					
Dimensions	TO-220AC 2L	www.vishay.com/doc?95259			
Difficusions	TO-220 FullPAK 2L	www.vishay.com/doc?95260			
Part marking information	TO-220AC 2L	www.vishay.com/doc?95391			
	TO-220 FullPAK 2L	www.vishay.com/doc?95392			
SPICE model	TO-220AC 2L	www.vishay.com/doc?96130			
	TO-220 FullPAK 2L	www.vishay.com/doc?96131			



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True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



CVMPOL	MILLII	METERS	INC	CHES
SYMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b ₁	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08	5.08 typical		typical
F	2.34	2.74	0.092	0.107
H ₁	6.50	6.90	0.256	0.272
J ₁	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L ₁	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q ₁	3.10	3.50	0.122	0.138
Q ₂	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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